HIGH FREQUENCY HIGH-SIDE AND LOW-SIDE GATE DRIVER IN V-QFN3030-8

Description

The DGD0590A is a high-frequency high-side and low-side gate driver capable of driving N-channel MOSFETs in a half-bridge configuration. The floating high-side driver is rated up to 40V and the provides a 5V gate drive to the MOSFETs.

The DGD0590A logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. A UVLO will protect ICs and MOSFETs with loss of supply.

Fast and well-matched propagation delays allow a higher switching frequency, enabling a smaller, more compact power switching design, using smaller associated components. The DGD0590A is offered in the V-QFN3030-8 package and operates over an extended -40°C to +125°C temperature range.

Features

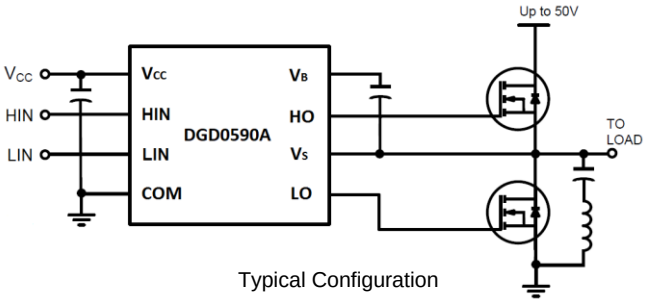
- 40V Floating High-Side Driver
- Low V_{CC} Operating Voltage: 4.5V to 5.5V
- Drives Two N-channel Logic Level MOSFETs in a Half-Bridge Configuration
- High-Side 1.0A Source / 1.0A Sink and Low-Side 1.0A Source / 3.0A Sink Output Current Capability
- Internal Bootstrap Diode Included
- 3.4V UVLO with 0.4V Hysteresis
- Fast Rise and Fall Times (27ns/17ns) with 3nF Load
- Propagation Delay Typical of 16ns for High-Side and 12ns for Low-Side
- Extended Temperature Range: -40°C to +125°C
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Applications

- Wireless Power Charger
- Motor Drive
- Logic Level MOSFET Gate Driver

Mechanical Data

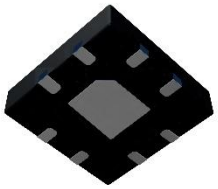
- Case: V-QFN3030-8 (Type TH)
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminals: Finish – Matte Tin Finish. Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.017 grams (Approximate)



Typical Configuration

V-QFN3030-8

Top View



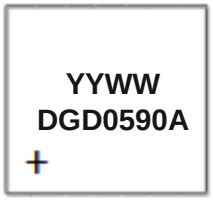
Bottom View

Ordering Information (Note 4)

Part Number	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
DGD0590AFU-7	DGD0590A	7	8	3,000

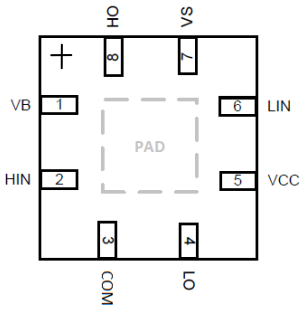
Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



DGD0590A = Product Type Marking Code
YY = Year (ex: 19 = 2019)
WW = Week (01 to 53)

Pin Diagrams

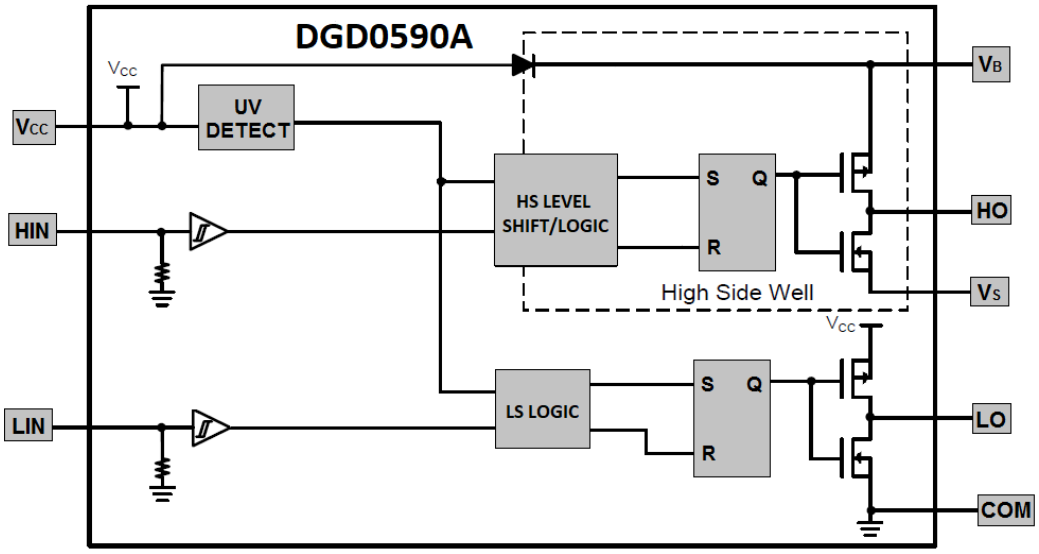


Top View: V-QFN3030-8

Pin Descriptions

Pin Number	Pin Name	Function
1	VB	High-Side Floating Supply
2	HIN	Logic Input for High-Side Gate Driver, in Phase with HO, Pull Down Resistor at Input
3	COM	Low-Side and Logic Return
4	LO	Low-Side Gate Driver Output
5	V_{CC}	Low-Side and Logic Supply
6	LIN	Logic Input for Low-Side Gate Driver, in Phase with LO, Pull Down Resistor at Input
7	VS	High-Side Floating Supply Return
8	HO	High-Side Gate Driver Output
PAD	Substrate	Connect to COM on PCB

Functional Block Diagram



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Positive Supply Voltage	V_B	0.3 to +50	V
High-Side Floating Negative Supply Voltage	V_S	V_B-6 to V_B+0.3	V
High-Side Floating Output Voltage	V_{HO}	V_S-0.3 to V_B+0.3	V
Offset Supply Voltage Transient	dV_S / dt	50	V/ns
Logic and Low-Side Fixed Supply Voltage	V_{CC}	-0.3 to +6	V
Low-Side Output Voltage	V_{LO}	-0.3 to V_{CC}+0.3	V
Logic Input Voltage (HIN and LIN)	V_{IN}	-0.3 to +6	V

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	120	°C/W
Thermal Resistance, Junction to Case (Note 5)	$R_{\theta JC}$	132	°C/W
Operating Temperature	T_J	+150	°C
Lead Temperature (Soldering, 10s)	T_L	+300	
Storage Temperature Range	T_{STG}	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply	V_B	V_S + 4.5	V_S + 5.5	V
High-Side Floating Supply Offset Voltage	V_S	0	40 (Note 6)	V
High-Side Floating Output Voltage	V_{HO}	V_S	V_B	V
Logic and Low Side Fixed Supply Voltage	V_{CC}	4.5	5.5	V
Low-Side Output Voltage	V_{LO}	0	V_{CC}	V
Logic Input Voltage (HIN and LIN)	V_{IN}	0	5	V
Ambient Temperature	T_A	-40	+125	°C

Note: 6. Provided V_B doesn't exceed absolute maximum rating of 50V.

DC Electrical Characteristics (V_{CC} = 5V, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Logic "1" Input Voltage, HIN	V_{HIH}	—	3.5	3.8	V	—
Logic "0" Input Voltage, HIN	V_{HIL}	1.0	1.3	—	V	—
Logic "1" Input Voltage, LIN	V_{LIH}	—	2.8	3.3	V	—
Logic "0" Input Voltage, LIN	V_{LIL}	1.0	1.2	—	V	—
Logic Input Bias Current	I_{IN+}	—	31	60	µA	$V_{IN} = V_{CC}$
V_{CC} Quiescent Supply Current	I_{CCQ}	—	22	50	µA	—
V_{CC} Operating Supply Current	I_{CCO}	—	300	—	µA	HO and LO Open, fs = 250kHz
High-Side Source Impedence	R_{HSO}	—	1.8	2.6	Ω	I_{SOURCE} = 100mA
High-Side Sink Impedence	R_{HSI}	—	1.5	2.1	Ω	I_{SINK} = 100mA
Low-Side Source Impedence	R_{LSO}	—	1.8	2.6	Ω	I_{SOURCE} = 100mA
Low-Side Sink Impedence	R_{LSI}	—	0.4	1.0	Ω	I_{SINK} = 100mA
V_{CC} Supply Undervoltage Positive Going Threshold	V_{CCUV+}	2.85	3.4	3.85	V	—
V_{CC} Supply Undervoltage Hysterisis	V_{CCU_HYST}	—	0.4	—	V	—
Bootstrap Diode Forward Voltage	V_{BFD}	—	650	800	mV	I = 100µA
Bootstrap Diode Reverse Leakage	I_{BDL}	—	0.1	0.4	µA	$V_B = V_S$ = 45.5V, V_{CC} = 0V

AC Electrical Characteristics (V_{CC} = 5V, C_L = 3nF, @T_A = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Turn-On Rise Time	t_R	—	27	—	ns	—
Turn-Off Fall Time, High-Side	t_F	—	29	—	ns	—
Turn-Off Fall Time, Low-Side		—	17	—	ns	—
Turn-On Propagation Delay Time, High-Side	t_{ONH}	—	16	—	ns	—
Turn-Off Propagation Delay Time, High-Side	t_{OFFH}	—	17	—	ns	—
Turn-On Propagation Delay Time, Low-Side	t_{ONL}	—	12	—	ns	—
Turn-Off Propagation Delay Time, Low-Side	t_{OFFL}	—	17	—	ns	—

Timing Waveforms

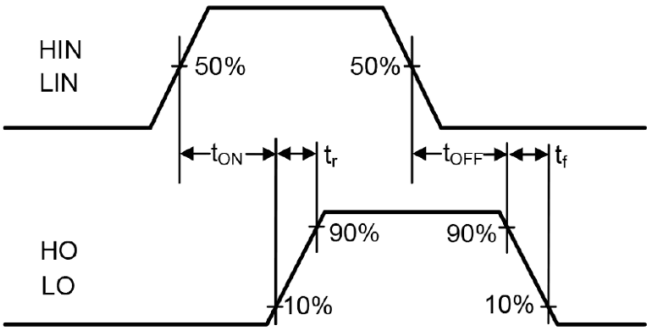


Figure 1. Switching Time Waveform Definitions

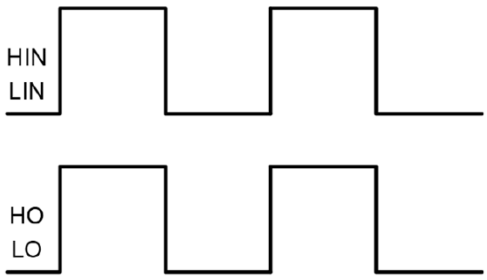


Figure 2. Input / Output Timing Diagram

Typical Performance Characteristics (@T_A = +25°C, unless otherwise specified.)

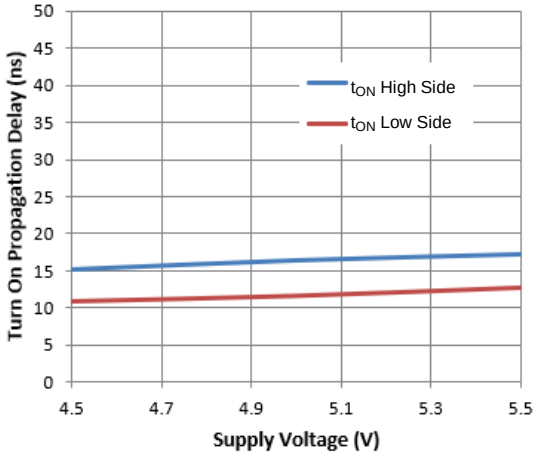


Figure 3. Turn-on Propagation Delay vs. Supply Voltage

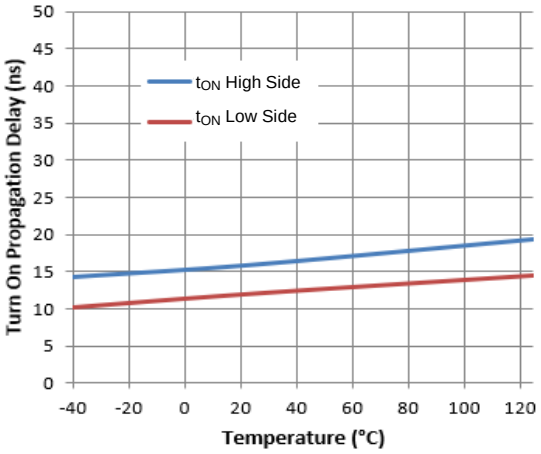


Figure 4. Turn-on Propagation Delay vs. Temperature

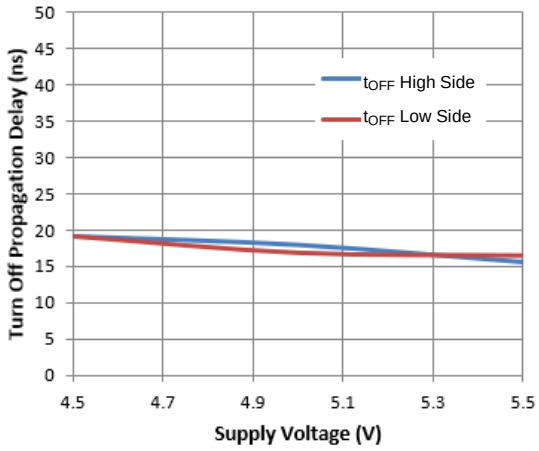


Figure 5. Turn-off Propagation Delay vs. Supply Voltage

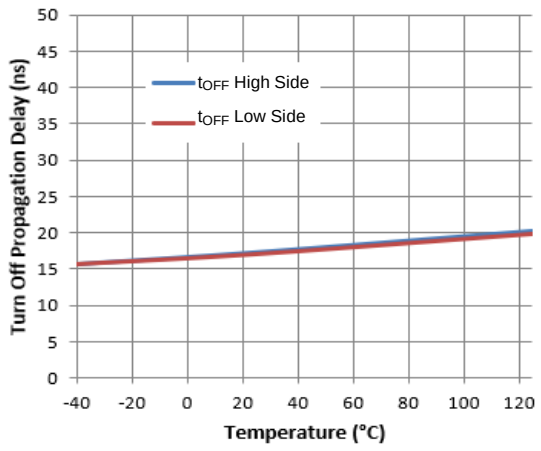


Figure 6. Turn-off Propagation Delay vs. Temperature

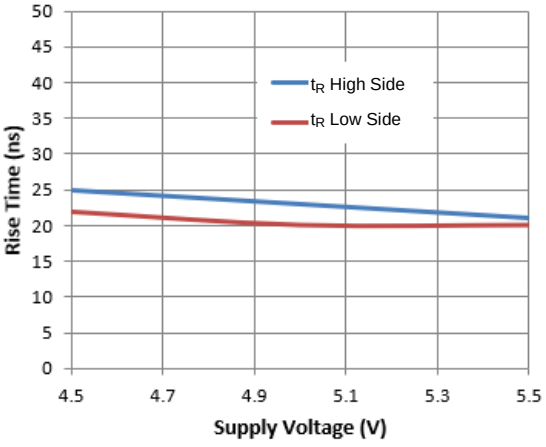


Figure 7. Rise Time vs. Supply Voltage

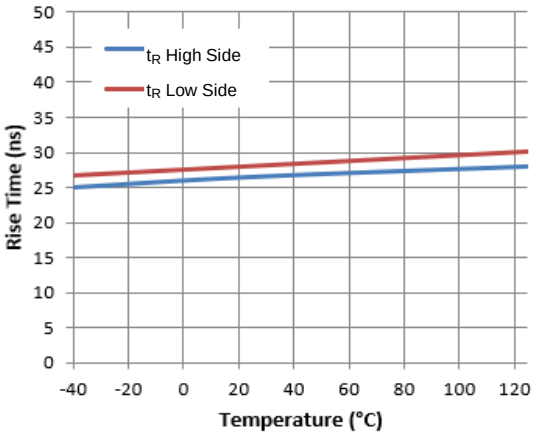


Figure 8. Rise Time vs. Temperature

Typical Performance Characteristics (continued)

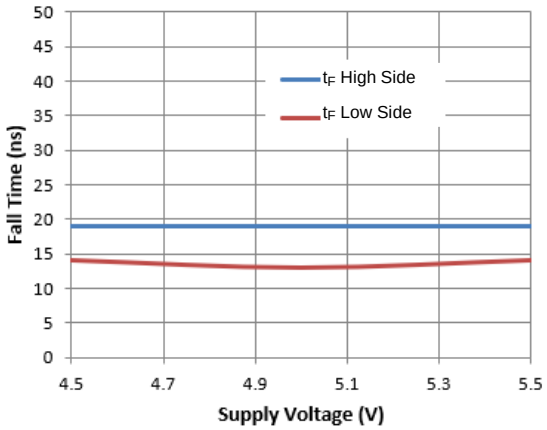


Figure 9. Fall Time vs. Supply Voltage

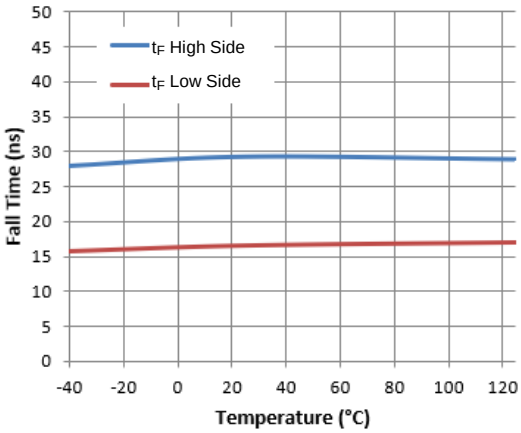


Figure 10. Fall Time vs. Temperature

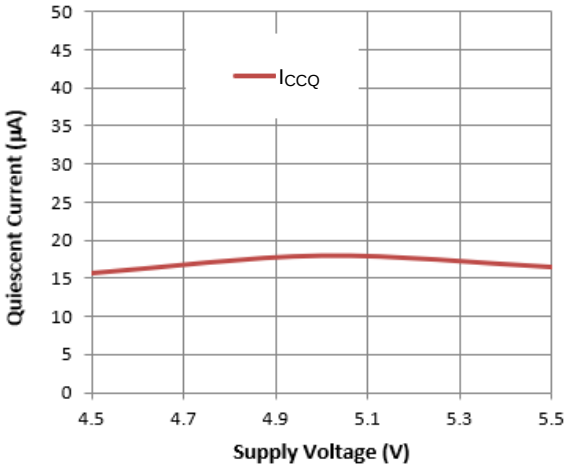


Figure 11. Quiescent Current vs. Supply Voltage

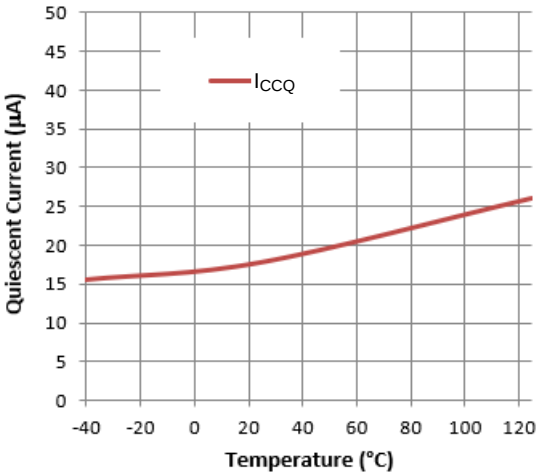


Figure 12. Quiescent Current vs. Temperature

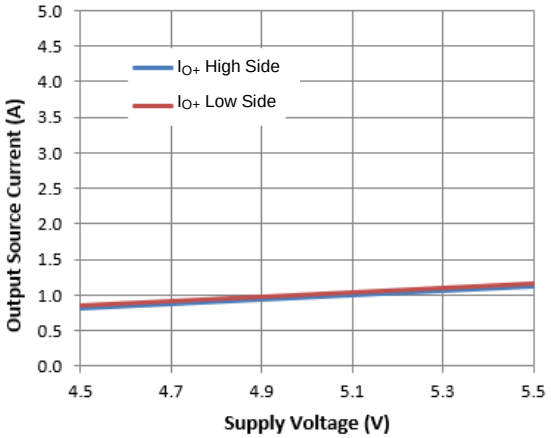


Figure 13. Output Source Current vs. Supply Voltage

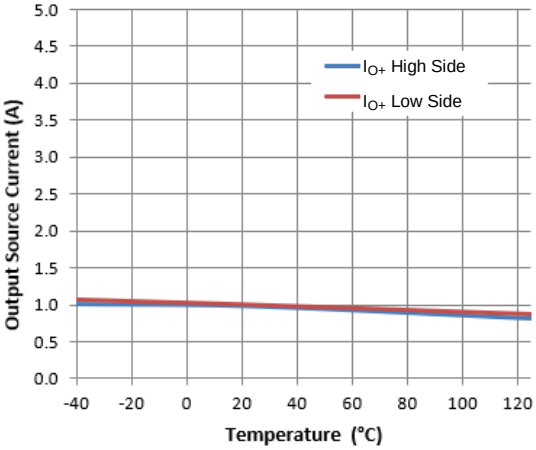


Figure 14. Output Source Current vs. Temperature

Typical Performance Characteristics (continued)

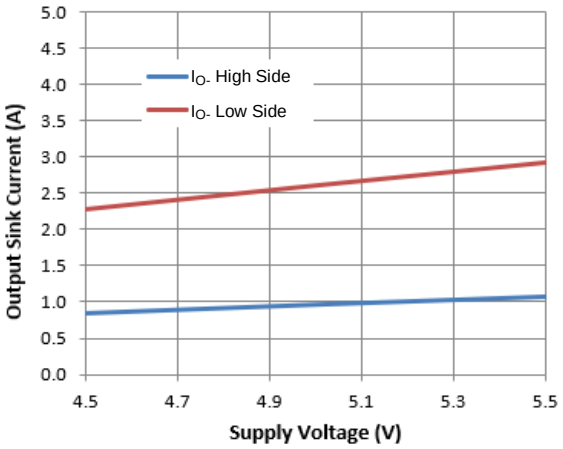


Figure 15. Output Sink Current vs. Supply Voltage

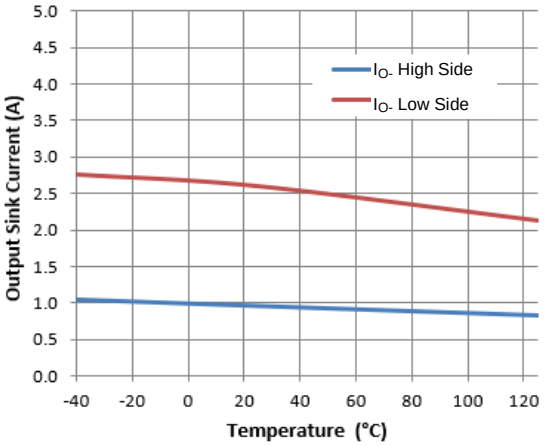


Figure 16. Output Sink Current vs. Temperature

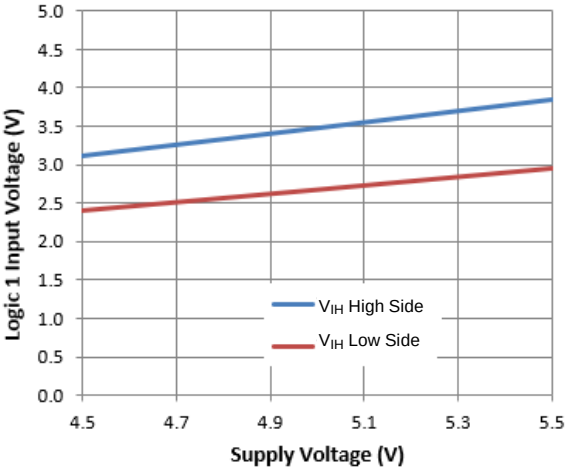


Figure 17. Logic 1 Input Voltage vs. Supply Voltage

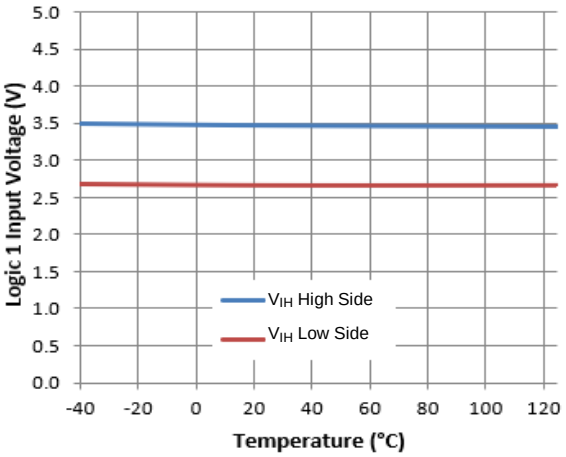


Figure 18. Logic 1 Input Voltage vs. Temperature

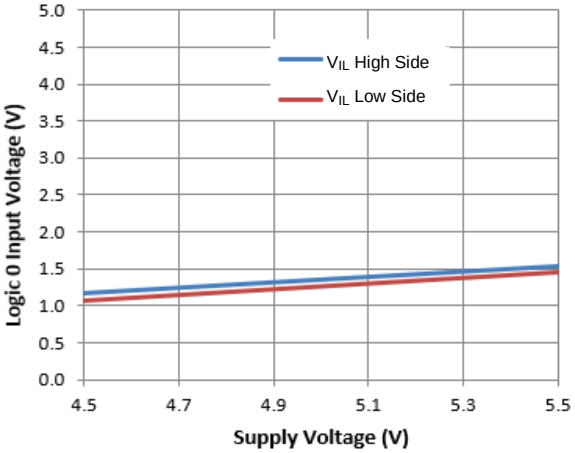


Figure 19. Logic 0 Input Voltage vs. Supply Voltage

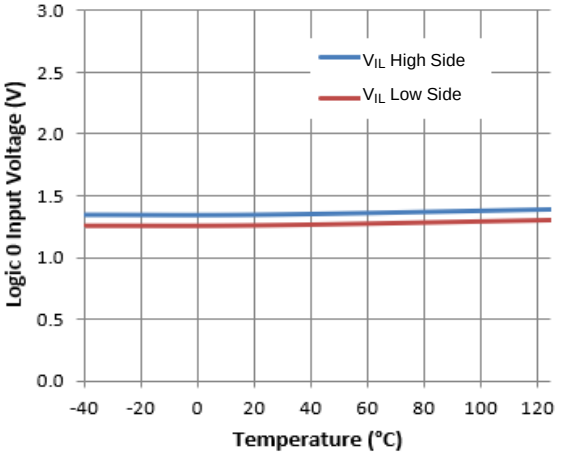


Figure 20. Logic 0 Input Voltage vs. Temperature

Typical Performance Characteristics (continued)

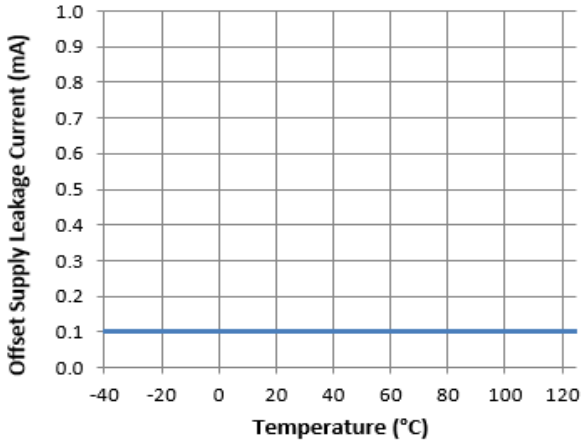
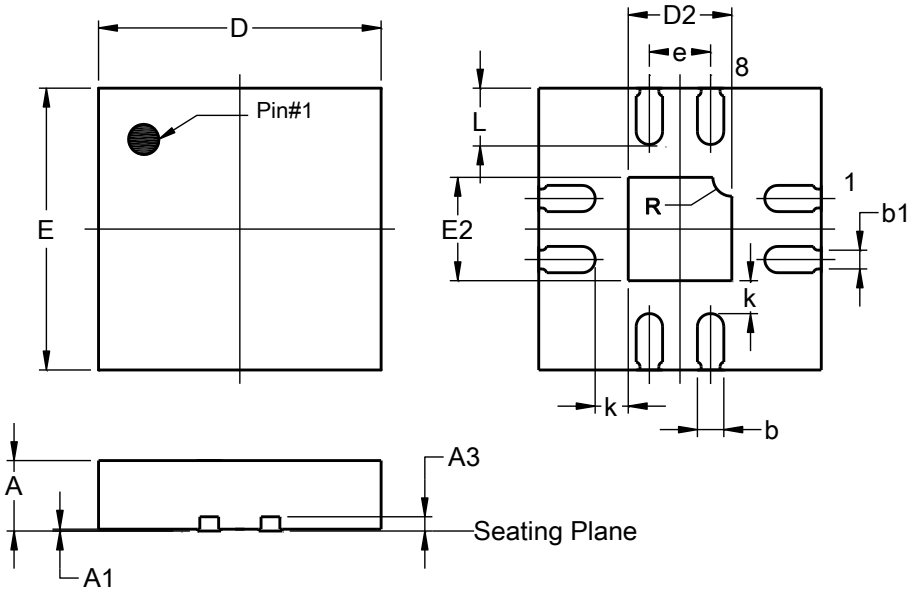


Figure 21. Offset Supply Leakage Current vs. Temperature

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-QFN3030-8 (Type TH)

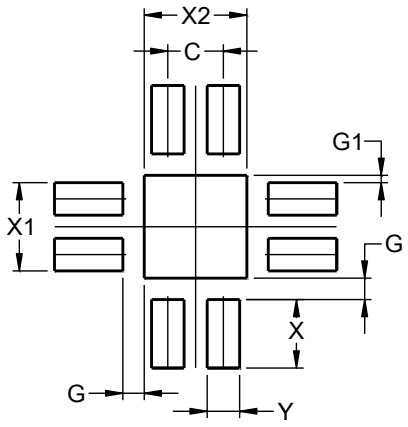


V-QFN3030-8 (Type TH)			
Dim	**Min**	**Max**	**Typ**
A	0.70	0.80	0.75
A1	0.00	0.05	0.02
A3	0.203REF		
b	0.23	0.33	0.28
b1	0.20REF		
D	2.90	3.10	3.00
D2	1.00	1.20	1.10
E	2.90	3.10	3.00
E2	1.00	1.20	1.10
e	0.65BSC		
L	0.55	0.65	0.60
k	0.30	0.40	0.35
R	0.20REF		
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

V-QFN3030-8 (Type TH)



Dimensions	Value (in mm)
C	0.650
G	0.250
G1	0.085
X	0.800
X1	1.030
X2	1.200
Y	0.380

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